


PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT23

Features

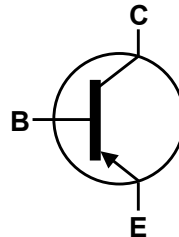
- Ideally Suited for Automatic Insertion
- Complementary NPN Types Available (BC846 – BC848)
- For switching and AF Amplifier Applications
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

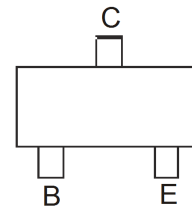
- Case: SOT23
- Case material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 
- Weight: 0.008 grams (Approximate)



Top View



Device Symbol



Top View
Pin-Out

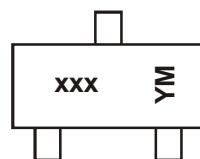
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC856A-7-F	AEC-Q101	K3A	7	3,000
BC856B-7-F	AEC-Q101	K3B	7	3,000
BC856BQ-7-F	Automotive	K3B	7	3,000
BC856B-13-F	AEC-Q101	K3B	13	10,000
BC856BQ-13-F	Automotive	K3B	13	10,000
BC857A-7-F	AEC-Q101	K3A	7	3,000
BC857B-7-F	AEC-Q101	K3B	7	3,000
BC857BQ-7-F	Automotive	K3B	7	3,000
BC857B-13-F	AEC-Q101	K3B	13	10,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC857C-7-F	AEC-Q101	K3G	7	3,000
BC857C-13-F	AEC-Q101	K3G	13	10,000
BC858A-7-F	AEC-Q101	K3A	7	3,000
BC858B-7-F	AEC-Q101	K3B	7	3,000
BC858C-7-F	AEC-Q101	K3G	7	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
 5. Tape width is 8mm. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



xxx = Product Type Marking Code
(Please see Ordering Information)
YM = Date Code Marking
Y = Year ex: X = 2010
M = Month ex: 9 = September

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Collector-Base Voltage	BC856	V _{CB0}	-80	V
	BC857		-50	
	BC858		-30	
Collector-Emitter Voltage	BC856	V _{CEO}	-65	V
	BC857		-45	
	BC858		-30	
Emitter-Base Voltage		V _{EBO}	-5.0	V
Continuous Collector Current		I _C	-100	mA
Peak Collector Current		I _{CM}	-200	mA
Peak Emitter Current		I _{EM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

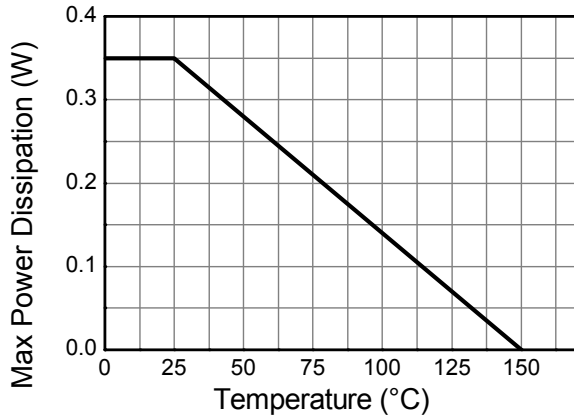
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P _D	310	mW
	(Note 7)		350	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	403	°C/W
	(Note 7)		357	
Thermal Resistance, Junction to Leads	(Note 8)	R _{θJL}	350	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 9)

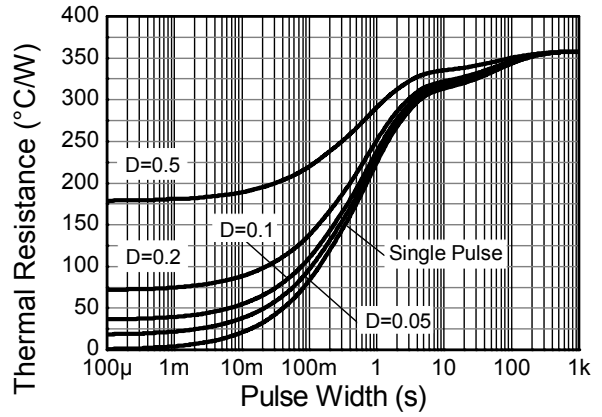
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 7. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 8. Thermal resistance from junction to solder-point (at the end of the leads).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

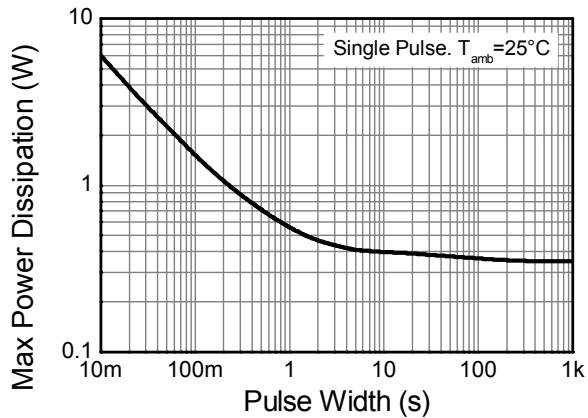
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BC856	BV _{CBO}	-80	—	—	V	I _C = -10μA
	BC857		-50				
	BC858		-30				
Collector-Emitter Breakdown Voltage (Note 10)	BC856	BV _{CEO}	-65	—	—	V	I _C = -10mA
	BC857		-45				
	BC858		-30				
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	—	—	V	I _E = -1μA
Collector Cutoff Current		I _{CBO}	—	—	-15 -4	μA	V _{CB} = -30V V _{CB} = -30V, T _A = +150°C
Collector Emitter Cutoff Current	BC856	I _{CES}	—	—	-15	nA	V _{CE} = -80V V _{CE} = -50V V _{CE} = -30V
	BC857				-15		
	BC858				-15		
Small Signal Current Gain (Note 10)	BC856A / BC857A / BC858A	h _{re}	—	—	200	—	I _C = -2.0mA, V _{CE} = -5V f = 1.0kHz
	BC856B / BC857B / BC858B				330		
	BC857C / BC858C				600		
Input Impedance (Note 10)	BC856A / BC857A / BC858A	h _{ie}	—	—	2.7	kΩ	
	BC856B / BC857B / BC858B				4.5		
	BC857C / BC858C				8.7		
Output Admittance (Note 10)	BC856A / BC857A / BC858A	h _{oe}	—	—	18	μS	
	BC856B / BC857B / BC858B				30		
	BC857C / BC858C				60		
Reverse Voltage Transfer Ratio (Note 10)	BC856A / BC857A / BC858A	h _{re}	—	—	1.5x10 ⁻⁴	—	
	BC856B / BC857B / BC858B				2x10 ⁻⁴		
	BC857C / BC858C				3x10 ⁻⁴		
DC Current Gain (Note 10)	BC856A / BC857A / BC858A	h _{FE}	—	—	125	—	I _C = -2.0mA, V _{CE} = -5V
	BC856B / BC857B / BC858B				220		
	BC857C / BC858C				420		
Collector-Emitter Saturation Voltage (Note 10)		V _{CE(sat)}	—	—	-75 -250 -300	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5.0mA
Base-Emitter Turn-On Voltage (Note 10)		V _{BE(on)}	-600	-650	-750 -820	mV	I _C = -2mA, V _{CE} = -5V I _C = -10mA, V _{CE} = -5V
Base-Emitter Saturation Voltage (Note 10)		V _{BE(sat)}	—	—	-700 -850	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5mA
Output Capacitance		C _{obo}	—	3	—	pF	V _{CB} = -10V, f = 1.0MHz
Transition Frequency		f _T	100	200	—	MHz	V _{CE} = -5V, I _C = -10mA, f = 100MHz
Noise Figure		NF	—	2	10	dB	V _{CE} = -5V, I _C = -200μA R _S = 2kΩ, f = 1kHz Δf = 200Hz

Notes: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

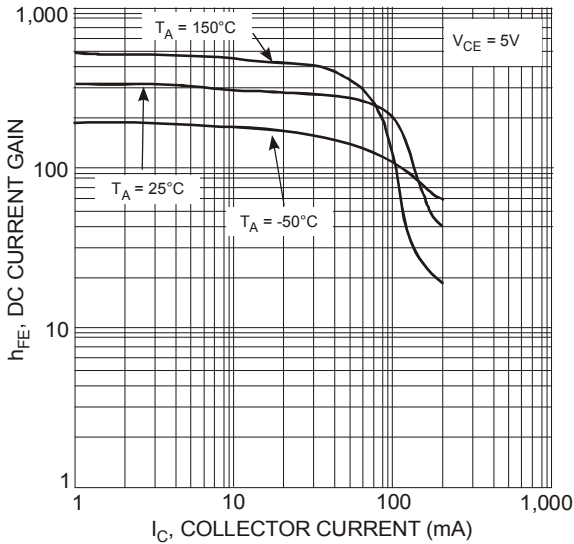


Figure 1 Typical DC Current Gain vs. Collector Current

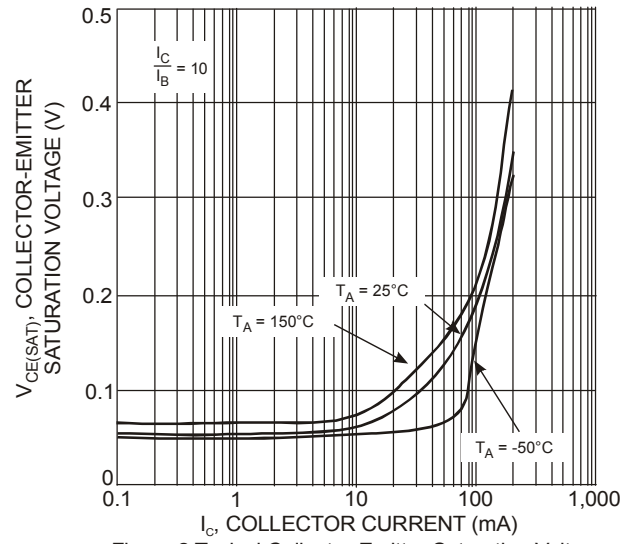


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

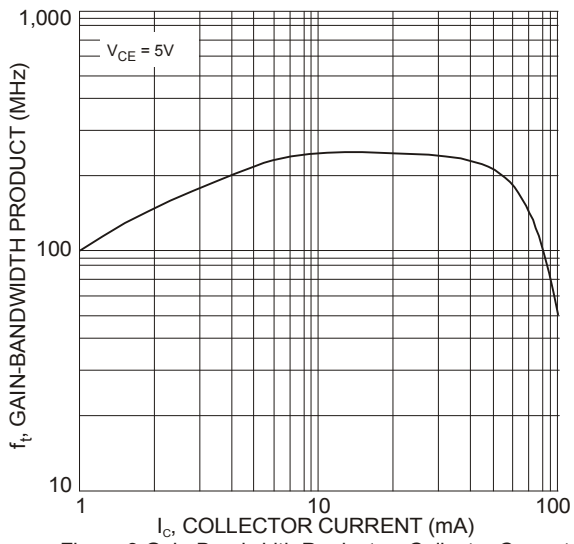
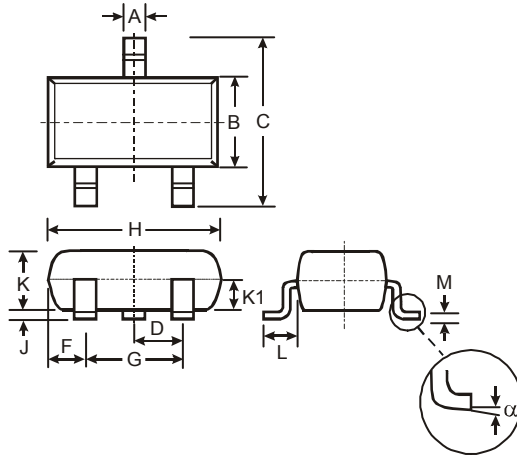


Figure 3 Gain-Bandwidth Product vs Collector Current

Package Outline Dimensions

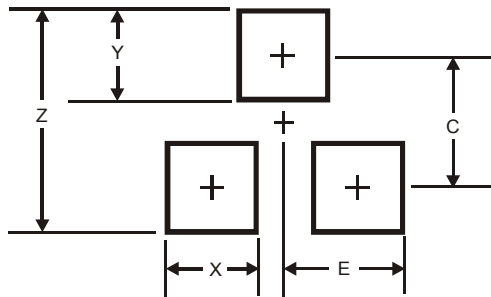
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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